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Received 3 Sep 2015 | Accepted 8 Jan 2016 | Published 10 Feb 2016

DOI: 10.1038/ncomms10672

OPEN

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Pure and stable metallic phase molybdenum disulfide nanosheets for hydrogen evolution reaction

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Metallic-phase MoS_2 (M-MoS₂) is metastable and does not exist in nature. Pure and stable M-MoS₂ has not been previously prepared by chemical synthesis, to the best of our knowledge. Here we report a hydrothermal process for synthesizing stable two-dimensional M-MoS₂ nanosheets in water. The metal-metal Raman stretching mode at $146 \, \text{cm}^{-1}$ in the M-MoS₂ structure, as predicted by theoretical calculations, is experimentally observed. The stability of the M-MoS₂ is associated with the adsorption of a monolayer of water molecules on both sides of the nanosheets, which reduce restacking and prevent aggregation in water. The obtained M-MoS₂ exhibits excellent stability in water and superior activity for the hydrogen evolution reaction, with a current density of $10 \, \text{mA} \, \text{cm}^{-2}$ at a low potential of $-175 \, \text{mV}$ and a Tafel slope of $41 \, \text{mV}$ per decade.

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he metallic-phase MoS₂ (M-MoS₂) is a single-layer S-Mo-S structure in which each molybdenum atom is surrounded by six sulfur atoms in an octahedral lattice. With dense active sites and an electronic conductivity that is six orders of magnitude higher than that of the semiconductor phase of MoS₂ (S-MoS₂) (ref. 1), M-MoS₂ has emerged as a promising candidate for a broad range of applications and is expected to exhibit better performance than its semiconducting counterpart, in particular in the hydrogen evolution reaction (HER) and as a photocatalyst and supercapacitor^{2–5}. These attractive properties of M-MoS₂ are offset by the fact that a pure phase of M-MoS₂ is very challenging to prepare, because it is highly unstable. Over the past few decades, many efforts to develop a process to prepare stable and highly pure M-MoS₂ have largely proved futile. A complicated method for the preparation of metastable M-MoS₂ using lithium intercalation of S-MoS₂ has been reported⁵⁻⁸. However, the reported M-MoS₂ suffered from coexistence with S-MoS₂ in a relative proportion of 50-80% (refs 3,9). In addition, the intermediary Li_xMoS₂ and intercalator of n-butyllithium are both dangerous materials that may self-heat⁸ and are highly pyrophoric in air⁵. The preparation procedures are also tedious and can take as long as 3 days^{10,11}. The previously mentioned M-MoS₂ easily transformed to S-MoS₂ due to S-S van der Waals interactions^{12–14}. Therefore, an efficient synthesis method for the production of a large quantity of stable and pure M-MoS₂ is still highly desirable.

M-MoS₂ could be an intermediary state during the synthesis of S-MoS₂, which is a stable form in many chemical reactions^{15,16}. This approach provides a possible method for capturing the metastable M-MoS₂ even though it is thermodynamically unstable and may rapidly transform to S-MoS2 at elevated temperatures. In fact, S-MoS₂ can transform into an octahedral structure of M-MoS₂ under a high pressure of 35 GPa (refs 17–19), which implies that the metallic phase of MoS₂ may be achievable at a relatively low temperature, a specific pressure and a proper chemical environment. Therefore, we employ octahedral MoO₃ as the starting material in a pressurized hydrothermal process, to directly grow highly pure M-MoS2 in water. The as-prepared M-MoS₂ is highly stable in water due to the reduced stacking of the layered materials, which are separated by water molecules. Urea, which is a weak reducing agent, plays a key role in the formation of M-MoS₂. The structure of octahedral MoO₃ can be maintained under acidic conditions. To satisfy the expected growth conditions, thioacetamide is chosen as the sulfur source and the reaction is maintained at a low pH value (pH \sim 4). The synthesis of M-MoS₂ is performed at 200 °C by mixing MoO₃, thioacetamide and urea in an autoclave. The as-prepared M-MoS₂ is pure and stable with high activity for the HER.

Results

Highly pure metallic phase MoS_2 . Figure 1a shows a typical scanning electron microscopic (SEM) image of the as-prepared M-MoS₂ sample. The MoS_2 nanosheets are 100 nm in size and a few nanometres in thickness. The morphology of S-MoS₂ is similar to that of M-MoS₂ on the nanoscale (Supplementary Fig. 1). The results from energy dispersive X-ray spectroscopy indicated that the S to Mo atomic ratio of the as-prepared M-MoS₂ is ~ 2.05 (Supplementary Fig. 2). The most notable difference between M-MoS₂ and S-MoS₂ is the symmetry of the sulfur in their structures. The structural variations result in significant differences in their characteristic Raman features. Figure 1b shows the Raman spectra of M-MoS₂ and S-MoS₂ synthesized at 200 °C and 240 °C, respectively. A strong Raman band is observed at 146 cm⁻¹ and attributed to Mo-Mo stretching vibrations in M-MoS₂. Calculations have predicted this band at the K points of the Brillouin zone for octahedrally

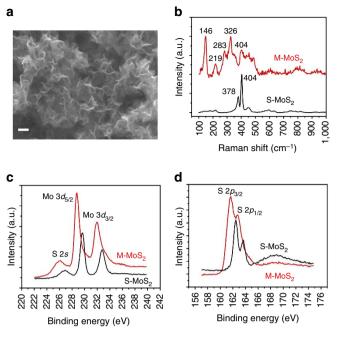


Figure 1 | Morphology of M-MoS₂ and phase identification of M-MoS₂ and S-MoS₂. (a) SEM image of M-MoS₂ showing the nanosheet structures. Scale bar, 100 nm. (b) Raman shift of M-MoS₂ and S-MoS₂. (c,d) High-resolution X-ray photoelectron spectroscopy (XPS) spectra of Mo 3d (c) and S 2p (d) for M-MoS₂ and S-MoS₂.

coordinated distorted MoS_2 (ref. 12). Our results confirm the existence of this band in M-MoS₂. The Raman shifts (that is, \sim 219, 283 and 326 cm⁻¹) are also associated with the phonon modes in M-MoS₂. S-MoS₂ exhibits typical Raman shifts of \sim 378 and 404 cm⁻¹ for E_{2g}^1 and A_{1g} , respectively, which are substantially different from those of M-MoS₂.

The phase identification of the synthesized M-MoS₂ and S-MoS₂ was further studied using X-ray photoelectron spectroscopy and the results are shown in Fig. 1c,d. The Mo 3d spectra consist of peaks located at approximately 228.7 and 231.8 eV, which correspond to the $3d_{5/2}$ and $3d_{3/2}$ components, respectively, of Mo^{4+} in M-MoS₂. However, the Mo 3d peaks of the M-MoS₂ samples also exhibit weak shoulders at the positions as those in S-MoS₂ due to the transformation of M-MoS₂ in vacuum and X-ray illumination. The details for the peak deconvolution are provided in Supplementary Fig. 3 and Supplementary Note 1. The Mo 3d peaks of M-MoS₂ shifted to lower binding energies by $\sim 1 \text{ eV}$ with respect to the corresponding peaks in S-MoS₂. This result is consistent with the previously obtained relaxation energy of 1 eV for M-MoS₂ derived from S-MoS₂ (refs 20,21). Similarly, the S 2p peaks of M-MoS₂ were located at \sim 161.6 and 162.7 eV, and associated with S $2p_{3/2}$ and $2p_{1/2}$, respectively, which are also $\sim 1 \, \text{eV}$ lower than the corresponding peaks in S-MoS₂. It is important to note that the prominent S peak located at $\sim 168 \,\mathrm{eV}$ was absent, indicating that the sulfur atoms remain unoxidized in M-MoS₂. However, this peak was observed in S-MoS₂ after annealing at 240 °C.

Morphologies and optical properties of MoS₂. Figure 2a shows optical images of the two types of MoS₂ dispersed in water. M-MoS₂ does not appear to exhibit bulk aggregation, whereas S-MoS₂ aggregates at the bottom of the solution. This result may be because M-MoS₂ possesses hydrophilic surfaces, whereas S-MoS₂ possesses relatively hydrophobic surfaces^{5,22}. After sonication, both M-MoS₂ and S-MoS₂ can uniformly

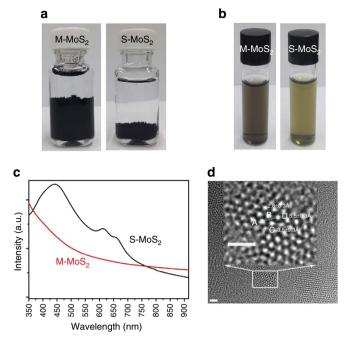


Figure 2 | Morphology and property of M-MoS₂ and S-MoS₂.(a) As-prepared M-MoS₂ and S-MoS₂ in water. (b) Suspension of M-MoS₂ and S-MoS₂ in water. (c) Ultraviolet-visible absorption of M-MoS₂ and S-MoS₂. (d) HRTEM image of M-MoS₂. The region indicated by the squares is enlarged to show the atomic structure of M-MoS₂. Scale bar, 1 nm.

disperse in water (Fig. 2b). However, M-MoS₂ was grey colour, whereas S-MoS₂ was green colour. These colours were associated with their optical properties, which were confirmed by optical absorption spectroscopy. Figure 2c shows the ultraviolet–visible absorption spectra of M-MoS₂ and S-MoS₂ in water. Two typical absorption peaks located at 613 and 660 nm were observed for S-MoS₂ and these peaks are associated with the energy split from the valence band spin–orbital coupling in S-MoS₂ with large lateral dimensions²³. In addition, another optical absorption band located at \sim 442 nm was observed. This band most probably results from the quantum effect of smaller lateral-sized S-MoS₂ nanosheets. The absorption spectrum of M-MoS₂ has no salient absorption bands but a monotonic change that is indicative of its metallic property.

The atomic structure of M-MoS₂ was investigated using a high-resolution scanning transmission electron microscope (HRTEM) at different magnifications (Supplementary Fig. 4) and the high-magnification image is shown in Fig. 2d. The hexagonal atomic arrangement of Mo indicates that each individual nanosheet consists of single crystal domains. Mo atoms on the basal plane have a Mo–Mo distance from A to D of 5.5 ± 0.3 Å, A to B of 2.8 ± 0.3 Å and A to C of 3.5 ± 0.3 Å. However, the crystal lattice may convert into an amorphous structure under the high-energy electron beam of TEM as observed by Lukowski *et al.*².

Stability of the M-MoS₂. The as-prepared M-MoS₂ nanosheets in water exhibited good stability over time. We believe that the high purity of M-MoS₂ plays an important role in its stability. 1T-MoS₂ (metallic phase), which was derived from 2H-MoS₂ (semiconductor phase), consists of electronic heterostructures of 2H-MoS₂ and 1T-MoS₂ in individual layers of MoS₂ (ref. 9). The coexistence of semiconductor MoS₂ with a metallic phase in a single layer resulted in an expedited transformation of 1T back to 2H MoS₂. Therefore, the structure was reported to be stable for 12 days with the observation of the 2H structure in water for

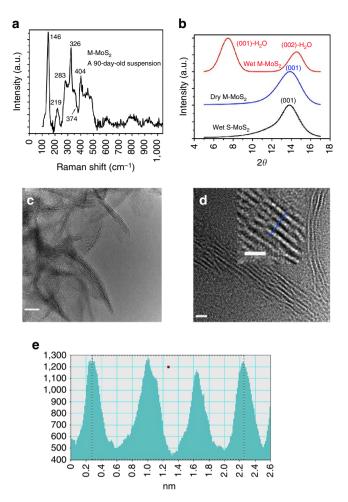


Figure 3 | Raman and structural characterization to investigate the stability of M-MoS₂. (a) Raman shift of M-MoS₂ stored for 90 days at room temperature. (b) XRD patterns of wet M-MoS₂, dry M-MoS₂ and wet S-MoS₂. (c) Low-resolution TEM image of M-MoS₂. Scale bar, 10 nm. (d) HRTEM image of M-MoS₂. The region indicated by the square is enlarged to show the layered structure of M-MoS₂. Scale bar, 2 nm. (e) Line scan of the HRTEM image indicated by the blue line in d, indicating a layer-to-layer spacing of 0.65 nm.

chemically exfoliated MoS₂ (ref. 12). The samples obtained in this study were stored in water for more than 90 days at room temperature and no obvious change in the Raman shift was observed (Fig. 3a). The characteristic peaks of the stored M-MoS₂ were similar to those observed for the freshly prepared samples. This observation indicates that the as-prepared M-MoS₂ was highly stable in water. It is important to note that a traceable transformation of M-MoS₂ to S-MoS₂ may occur, as suggested by the very weak shoulder at 374 cm⁻¹. The pure metallic phase in the individual layers contributes to the stability of the material. A comparison of the Raman spectra of M-MoS₂ stored under different conditions and S-MoS₂ is shown in Supplementary Fig. 5.

Another possible stability mechanism may arise from the monolayer of water molecules that was adsorbed on both sides of the M-MoS₂ nanosheets. This layer prevents aggregation and stacking, and maintains the octahedral structure in M-MoS₂. The existence of the water molecule layer was confirmed by XRD measurements (Fig. 3b). The peak at 7.5°, which corresponds to a spacing of 11.8 Å, was identified as (001)-H₂O for M-MoS₂-H₂O, which contains a bilayer of water molecules between the adjacent layers of MoS₂ nanosheets²⁴. As the layer thickness of MoS₂ was

 \sim 6.2 Å and the thickness of a monolayer of water was 2.8 Å, the total thickness of a MoS₂ layer surrounded by a water bilayer would be 11.8 Å. This result was previously confirmed by XRD²⁵. The peak located at 14.6° was assigned to the second-order reflection of M-MoS₂-H₂O.

XRD was also performed on the M-MoS₂ nanosheets after they were dried for 24 h in a vacuum chamber at a pressure of 6 mTorr. The XRD pattern of the dried M-MoS₂ is similar to that of S-MoS₂ with a peak at 13.88° (Fig. 3b), which corresponds to the stacked M-MoS₂ multilayers. This result suggests that the spacing between the Mo planes for M-MoS₂ was 6.4 ± 0.1 Å. This spacing is larger than that of bulk MoS₂ (that is, 6.15 Å). The diffraction peak at 7.5° disappeared due to desorption of the water molecules on the nanosheet surfaces. The TEM and HRTEM images indicate that M-MoS2 was composed of singlelayer or several-layer structures (Fig. 3c,d). The lattice fringe spacing of M-MoS₂ was measured to be 1.97 nm for a four-layer nanosheet, which produced a Mo-Mo spacing of $6.5 \pm 0.1 \,\text{Å}$ (Fig. 3e). This result is consistent with the value obtained from the XRD measurements. The increased interlayer spacing in M-MoS₂ may contribute to its stability due to the weakened S-S van der Waals interactions and reduced restacking probability.

M-MoS₂ contained adsorbed water molecules, which was confirmed by XRD measurements. However, this phenomenon was not observed in S-MoS2 nanostructures. This difference between the two phases of MoS2 reflects the different surface properties (that is, M-MoS₂ is hydrophilic, whereas S-MoS₂ is hydrophobic). These properties are determined by the atomic structures of M-MoS₂ and S-MoS₂. The Mo atom in M-MoS₂ is located in an octahedral S coordination, whereas the Mo atom in S-MoS₂ coordinated by six S atoms in a trigonal prismatic arrangement with S acting as a hydrophobic site and Mo serving as a hydrophilic site²⁶. These different surface properties were also observed regardless of whether they were dispersed in water or deposited as thin films on substrates (Supplementary Fig. 6). Contact angle measurements were conducted on both the M-MoS₂ and S-MoS₂ films. A contact angle of 25° was observed for M-MoS2 and an angle of 118° was determined for S-MoS₂, confirming the highly hydrophilic surface of M-MoS₂. The details are provided in Supplementary Fig. 7.

Metallic phase MoS₂ for HER. The different surface properties, atomic structure and morphology of M-MoS2 and S-MoS2 on substrates led to significant differences in the HER. Hydrogen production measurements were conducted for the M-MoS₂ and S-MoS₂ nanosheets deposited on glassy carbon electrodes using a three-electrode cell in a 0.5-M sulfuric acid electrolyte. Figure 4a,b show the polarization curves and corresponding Tafel plots of the M-MoS₂ and S-MoS₂ nanosheets compared with those of Pt. It is important to note that the Tafel plot employs a logarithmic current density axis. A low potential of -175 mV at a current density of 10 mA cm⁻² and a Tafel slope of 41 mV per decade were obtained for M-MoS₂. This observed potential for hydrogen production represents the lowest value among the reported experimental data for the use of only MoS₂ materials. The long-term stability of the M-MoS₂ electrode for the HER was investigated. After 1,000 cycles of continuous operation, the exfoliated MoS₂ nanosheets exhibited <12% decay in the electrocatalytic current density (Fig. 4c). The advantage of using M-MoS₂ nanosheets becomes more apparent through electrochemical impedance spectroscopy analysis. The electrochemical impedance spectroscopy was performed under the HER conditions. The Nyquist plots are shown in Fig. 4d and revealed a dramatically decreased charge transfer resistance for the M-MoS₂ nanosheets ($\sim 1 \Omega$) relative to the S-MoS₂ nanosheets ($\sim 50 \Omega$). Furthermore, we measured the resistivity of the M-MoS₂ (300 nm

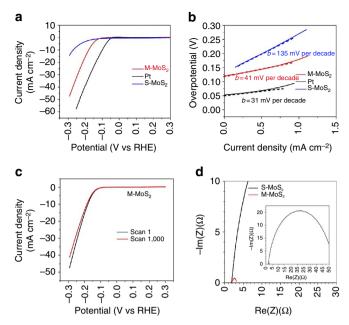


Figure 4 | HER activity of the synthesized MoS_2 nanosheets. (a) Polarization curves of the M-MoS₂ and S-MoS₂ nanosheets. (b) Corresponding Tafel plots obtained from the polarization curves. The Tafel slopes were \sim 41 and \sim 135 mV per decade for M-MoS₂ and S-MoS₂, respectively. (c) Polarization curves of the M-MoS₂ nanosheets after 1 and 1,000 cycles of continuous operation. (d) Nyquist plots of M-MoS₂ and S-MoS₂.

thick) and S-MoS₂ (340 nm thick) films using a four-probe method under ambient conditions. The sheet resistances are $1.61\times10^4~\Omega/\Box$ for M-MoS₂ and $2.26\times10^9~\Omega/\Box$ for S-MoS₂, which correspond to a resistivity of $0.482~\Omega\cdot$ cm for M-MoS₂ and $7.68\times10^4~\Omega\cdot$ cm for S-MoS₂. This result indicates that M-MoS₂ has a conductivity that is five orders of magnitude higher than that of S-MoS₂.

It is important to note that the growth of M-MoS₂ and the HER measurements are highly reproducible. The growth process of M-MoS₂ failed only once in 96 trials. The failure was caused by washing the autoclave with HNO₃ and we believe that a trace amount of residual HNO₃ may have oxidized the products via different chemical reactions. The autoclave was typically cleaned by sonication in water. We have performed the HER 62 times using our synthesized M-MoS₂ and all of the trials yielded results similar to those shown in Fig. 4a,b. The exceptional performance of M-MoS₂ for hydrogen production may be due to the high purity, dense active sites, good conductivity and excellent hydrophilic property of M-MoS₂. By contrast, S-MoS₂ exhibited little HER activity with a potential of $-274 \,\mathrm{mV}$ at $10 \,\mathrm{mA}\,\mathrm{cm}^{-2}$ and a Tafel slope of 135 mV per decade. The poor performance of S-MoS₂ in the HER was due to few active sites, aggregation and its hydrophobic surface. The exchange current density of M-MoS₂, S-MoS₂ and Pt is discussed in Supplementary Discussion. Although M-MoS₂ still lags behind Pt, improvement in the HER activity can be accomplished by enhancing the conductivity of the nanoscale M-MoS₂. Therefore, metallic MoS₂ exhibits great potential for use as a replacement for Pt in the HER as a low-cost and highly active catalyst for practical applications.

Discussion

The mechanism underlying the formation of the stable metallic phase of MoS_2 is directly associated with the weak reducer urea, which can precisely and effectively reduce MoO_3 to $M-MoS_2$ as shown in equation (1). The absence of a urea reducer while

maintaining other growth conditions would result in a product dominated by amorphous MoS₃, as shown in equation (2) (see Supplementary Methods and Supplementary Fig. 8). Other reducers, such as hydrazine, reduce MoO₃ to S-MoS₂ only due to the relatively strong electron donating ability of hydrazine.

$$\begin{array}{l} MoO_3 + 3CH_3CSNH_2 + NH_2CONH_2 + 5O_2 \overset{200 \deg C}{\rightarrow} M\text{-MoS}_2 \downarrow \\ + CH_3CONH_2 + (NH_4)_2S + N_2 \uparrow + 5CO_2 \uparrow + 3H_2O \end{array} \tag{1}$$

$$MoO_3 + 3CH_3CSNH_2 \xrightarrow{200 \deg C/2h} MoS_3 \downarrow (Gel - sol) + 3CH_3CONH_2$$
(2)

$$MoO_3 + 3CH_3CSNH_2 + NH_2CONH_2 + 5O_2 \xrightarrow{240 \text{ deg C}} S-MoS_2 \downarrow$$

+ $CH_3CONH_2 + (NH_4)_2S + N_2 \uparrow + 5CO_2 \uparrow + 3H_2O$ (3)

During the synthesis of M-MoS₂, the three most important factors are solvent, pH and temperature. First, water serves as a solvent and is adsorbed on the surface of M-MoS2 to form a water molecular layer that prevents layer stacking. When an organic solvent, such as ethanol or dimethylformamide, was added to the reaction, no desirable product was produced (see the Supplementary Methods and Supplementary Fig. 9). No solid product was found in the autoclave when a 1:1 ratio of water to ethanol was used. Second, the pH controls the steric structure of the starting materials and the formation of M-MoS₂. When the pH value was ≤ 4 , the octahedral coordination of MoO₃ can be maintained, which may lead to the formation of M-MoS₂. At higher pH values (pH 8) achieved through the addition of ammonia, the MoO₃ structure converts into MoO₄²⁻ tetrahedral centres. This change causes the reaction to yield no desirable products. Third, the temperature also plays a key role in the formation of M-MoS₂. In this study, pure M-MoS₂ was obtained at 200 °C and S-MoS2 was formed at 240 °C in the reaction listed in equation (3).

Based on these discussions, the metastable M-MoS₂ intermediate can be formed and stabilized in a pressurized hydrothermal process with a suitable reducer and temperature. The proposed mechanism involves the formation of a crystal phase of M-MoS₂ from amorphous clustered MoS₃ with S₂ edge bonds reduced by urea. In fact, many investigations have revealed the structural evolution from MoS_3 to $S-MoS_2$ without the MoS_2 metallic phase during the evolution process^{27–29}. We believe that the high temperature and strong reducer used in the previous studies may have only resulted in the formation of semiconductor MoS₂. This result was also confirmed in this study, because only S-MoS₂ was obtained when the temperature was increased to 240 °C. The evolution process for the formation of M-MoS₂ is shown in Fig. 5, which illustrates the growth of MoS₃ from one cluster to two and finally to a nanosheet. The central part possesses the structure of M-MoS₂ and the S₂⁻ bond on the edge can be removed by urea to continue the growth to form a single layer of M-MoS₂ (ref. 30). A control experiment was carried out by stopping the growth after 90 min, which resulted in a mixture of MoS₃ and M-MoS₂ in the solution. The existence of MoS₃ and its corresponding peak at $120 \,\mathrm{cm}^{-1}$ peak was confirmed by Raman spectroscopy³¹. Furthermore, a Raman band located at $548 \,\mathrm{cm}^{-1}$, which was due to the S_2^- stretching vibration in MoS₃, was observed. Energy dispersive X-ray spectroscopy measurements indicate a ratio of 1:3 for Mo and S (See Supplementary Fig. 10b). The Mo-Mo vibration mode at 146 cm⁻¹ starts to appear and become more prominent as growth time increased, indicating the transformation of MoS₃ to M-MoS₂ (see Supplementary Fig. 10c). After continuing the reaction for 6 h, only M-MoS₂ was observed in the product. At this point, the Raman peak located at 120 cm⁻¹ disappeared and

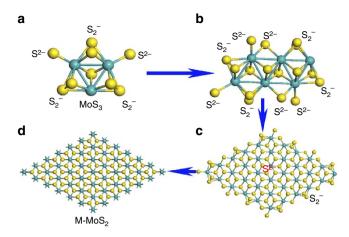


Figure 5 | Schematic illustrations of the evolution process of M-MoS₂ from MoS₃. (a) One MoS₃ cluster with S²⁻ and S₂⁻. (b) Combination of two MoS₃ clusters with the breaking of S₂⁻. (c) Several MoS₃ cluster forming MoS₂ with S²⁻ in the centre and MoS₃ with S₂⁻ at the edge. (d) Stable M-MoS₂ crystal structure.

the intensity of the 146 cm⁻¹ peak reached its maximum. This result indicates the complete conversion of MoS₃ to M-MoS₂.

A hydrothermal process has been used to grow S-MoS₂. To the best of our knowledge, the preparation of M-MoS2 using a hydrothermal method has not been previously reported. We believe that the growth conditions used in this study play a key role in the formation and stabilization of M-MoS₂. M-MoS₂ is an unstable phase that can easily transform to S-MoS₂. Therefore, the octahedral coordination of M-MoS2 must be maintained during deposition. For this reason, we used MoO₃ as the starting material, because it possesses the same octahedral structure as M-MoS₂. The metallic phase can be obtained when the crystal structure can be maintained during the conversion process from MoO₃ to MoS₂. Urea, which is a weak reducer, is able to maintain the crystal structure at a low pH value and optimum temperature (200 °C) for hydrothermal growth. As mentioned in the previous sections, only S-MoS₂ was obtained at a higher growth temperature of 240 °C, because the octahedral structure of M-MoS₂ cannot be maintained under the growth conditions used. Once the M-MoS₂ nanosheets were formed at 200 °C, the adsorption of water molecules on their surfaces due to the hydrophilic nature of the surface provides an environment to maintain the octahedral structure and preventing restacking of the layers. Therefore, M-MoS2 can be stored in water for several months without significant transition to S-MoS2. However, once M-MoS2 is removed from water and dried in a vacuum, it will slowly convert to S-MoS2. This observation indicates that the stability of M-MoS₂ is dependent on the environment. Although this study was focused on the influence of water, the environmental stability of M-MoS2 under other conditions, such as different gases and solutions other than water, should be considered in future investigations.

In conclusion, highly pure and stable M-MoS₂ nanosheets were synthesized in solution using a rational and controllable approach. A unique Raman peak located at 146 cm⁻¹ due to M-MoS₂ was experimentally observed, which confirms the theoretical prediction. A growth mechanism was proposed and is supported by the experimental data. Excellent activity of M-MoS₂ for the HER was achieved and the material has the potential to replace Pt in practical applications. These results provide opportunities for studying the metallic phase of MoS₂, which has potential technological applications in renewable energy, energy storage and heterogeneous catalysis.

Methods

Preparation of M-MoS₂ and S-MoS₂. MoO₃ powder (CAS number is 1311-27-5) and urea (CAS number is 57-13-6) were purchased from the Sigma-Aldrich Company. Thioacetamide (CAS number is 62-55-5) was purchased from the Fisher Scientific Company. The autoclave (model number 4749) was ordered from the Parr Instrument Company.

Twelve milligrams of MoO₃, 14 mg of thioacetamide and 0.12 g of urea were dissolved in 10 ml of deionized water and stirred for 2 h. Then, the solution was placed in an autoclave and loaded into a furnace (from MTI), which has been heated to 200 °C. The temperature of the oven was maintained at 200 °C for 12 h. Next, the reaction was terminated by rapidly cooling the solution to room temperature by removing the autoclave from the oven. The prepared M-MoS₂ was collected and washed with deionized water several times, followed by storage in deionized water before use. The same procedure was used to synthesize S-MoS₂ at 240 °C. Two-dimensional nanosheets were observed and no significant difference was observed between M-Mo₂ and S-MoS₂ based on their nanoscale morphology.

Ultraviolet-visible-infrared spectroscopy. Ultraviolet-visible-infrared absorption spectroscopy of the M-MoS₂ and S-MoS₂ dispersions in water were recorded using a Perkin Elmer Lambda 25 spectrophotometer.

TEM observations. TEM and HRTEM images and electron diffraction were performed on a FEI Tecnai G2 F20 S-Twin microscope operated at an accelerating voltage of up to 200 kV. The TEM samples were prepared by sonication at 500 W for $\sim 5\,\text{min}$ and $25\,\mu\text{l}$ of the supernatant were dropped onto holey carbon grids.

SEM observations. The SEM images were obtained using a field-emission gun SEM (Quanta 400 FEG FEI). The samples were dispersed in water and then dropped onto the Si/SiO_2 substrates.

X-ray photoelectron spectroscopy. X-ray photoelectron spectroscopy was conducted using an Axis Ultra DLD (Kratos) system. The vacuum of the chamber was 1×10^{-9} Torr. A monochromatic aluminum K_α source with a source power of $150 \,\mathrm{W} \, (15 \,\mathrm{kV} \times 10 \,\mathrm{mA})$ was used. The pass energy was $160 \,\mathrm{eV}$ for wide scans and $40 \,\mathrm{eV}$ for narrow scans.

Raman spectroscopy. Raman spectroscopy was performed using a LabRam HR800 UV NIR and 532-nm laser excitation with working distances on a \times 50 lens. The Raman spectra of M-MoS $_2$ and S-MoS $_2$ were recorded by depositing the samples on silicon substrates.

XRD patterns. The XRD patterns of M-MoS₂ and S-MoS₂ were recorded for two theta values ranging from 4° to 18°, to characterize the interlayer spacing. The characterization was performed on a Bruker AXS-D8 Advance powder X-ray diffractometer using Cu/Ka radiation (λ = 1.5406 Å) with a step size of 0.02° and a dwell time of 3.0 s.

Electrocatalytic hydrogen evolution. The electrochemical measurements were performed using a three-electrode electrochemical station (Gamry Instruments). All of the measurements were performed in a solution consisting of 50 ml of a 0.5-M H₂SO₄ electrolyte prepared using 18 M deionized water purged with H₂ gas (99.999%). The MoS₂ suspension in water was dropped onto glassy carbon as the working electrode. All of the working electrodes were prepared using the MoS2 solutions. The solution concentrations of M-MoS2 and S-MoS2 were \sim 0.3 mg ml⁻¹ and \sim 0.4 mg ml⁻¹, respectively, in water. The diameter of the glass carbon electrode was 0.3 cm and the area was \sim 0.07 cm². The amount of deposited catalyst on the electrode was \sim 43 μg cm⁻² for M-MoS₂ and 114 μg cm⁻² for S-MoS₂. Platinum foil was used as the counter electrode and a saturated calomel was used as the reference electrode. The reversible hydrogen electrode was calibrated using platinum as both the working and counter electrodes to +0.3 V versus the saturated calomel reference electrode. The performance of the hydrogen evolution catalyst was measured using linear sweep voltammetry from +0.3 to -0.3 V versus reversible hydrogen electrode with a scan rate of $5\,mV\,s^{\,-\,1}.$

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Acknowledgements

This work was supported by the National Science Foundation of US (Award Number EPS-1003970) and the NASA RID programme. We thank Dr Allan Thomas for discussions on the electrochemical impedance spectroscopy measurements. We thank the Center for Integrative Nanotechnology Sciences at the UALR for experimental assistance.

Author contributions

X.G., T.C. and J.C. conceived and designed the experiments. X.G. and J.C wrote the paper with input from all of the authors. B.C. edited the manuscript. All of the experimental work was conducted by X.G with W.W., W.S., A.A., M.B., H.Z., F.W. and J.C. The

experimental data were analysed by X.G. with J.C. and T.C., and the results were discussed by all of the authors.

Additional information

 ${\bf Supplementary\ Information\ } accompanies\ this\ paper\ at\ http://www.nature.com/naturecommunications$

Competing financial interests: The authors declare no competing financial interests.

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How to cite this article: Geng, X. *et al.* Pure and stable metallic phase molybdenum disulfide nanosheets for hydrogen evolution reaction. *Nat. Commun.* 7:10672 doi: 10.1038/ncomms10672 (2016).

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